

# 2SC4134T-E Datasheet



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DiGi Electronics Part Number	2SC4134T-E-DG
Manufacturer	<a href="#">onsemi</a>
Manufacturer Product Number	2SC4134T-E
Description	TRANS NPN 100V 1A TP
Detailed Description	Bipolar (BJT) Transistor NPN 100 V 1 A 120MHz 800 mW Through Hole TP



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RFQ Email: [Info@DiGi-Electronics.com](mailto:Info@DiGi-Electronics.com)

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## Purchase and inquiry

Manufacturer Product Number:

2SC4134T-E

Series:

-

Transistor Type:

NPN

Voltage - Collector Emitter Breakdown (Max):

100 V

Current - Collector Cutoff (Max):

100nA (ICBO)

Power - Max:

800 mW

Operating Temperature:

150°C (TJ)

Package / Case:

TO-251-3 Short Leads, IPak, TO-251AA

Base Product Number:

2SC4134

Manufacturer:

onsemi

Product Status:

Active

Current - Collector (Ic) (Max):

1 A

Vce Saturation (Max) @ Ib, Ic:

400mV @ 40mA, 400mA

DC Current Gain (hFE) (Min) @ Ic, Vce:

200 @ 100mA, 5V

Frequency - Transition:

120MHz

Mounting Type:

Through Hole

Supplier Device Package:

TP

## Environmental & Export classification

RoHS Status:

ROHS3 Compliant

REACH Status:

REACH Unaffected

HTSUS:

8541.21.0075

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

EAR99

Ordering number : EN2510B



# 2SC4134

## Bipolar Transistor 100V, 1A, Low VCE(sat), NPN Single TP/TP-FA

ON Semiconductor®

http://onsemi.com

### Applications

- Power supplies, relay drivers, lamp drivers

### Features

- Adoption FBET, MBIT processes
- Fast switching speed
- Small and slim package permitting 2SC4134-applied sets to be made more compact
- High breakdown voltage and large current capacity

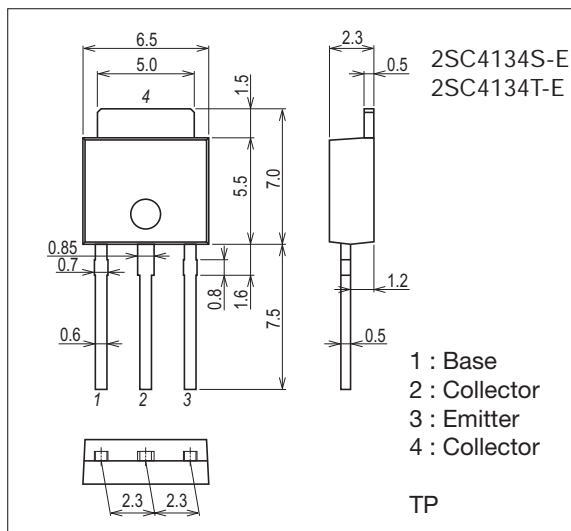
### Specifications

Absolute Maximum Ratings at Ta=25°C

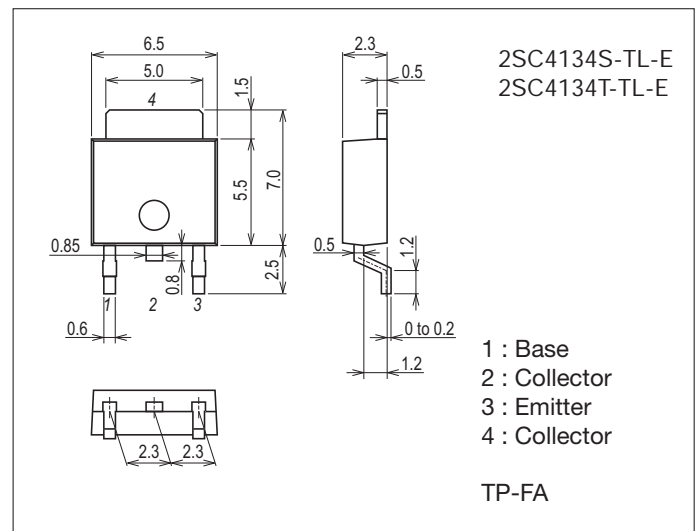
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CB0</sub>		120	V
Collector-to-Emitter Voltage	V <sub>CEO</sub>		100	V
Emitter-to-Base Voltage	V <sub>EB0</sub>		6	V
Collector Current	I <sub>C</sub>		1	A
Collector Current (Pulse)	I <sub>CP</sub>		2	A

Continued on next page.

### Package Dimensions unit : mm (typ) 7518-003



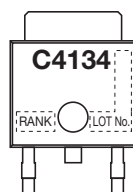
### Package Dimensions unit : mm (typ) 7003-003



### Product & Package Information

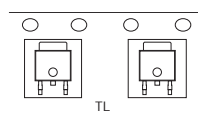
- Package : TP
- JEITA, JEDEC : SC-64, TO-251
- Minimum Packing Quantity : 500 pcs./bag

### Marking (TP, TP-FA)

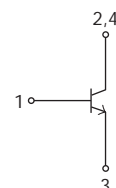


- Package : TP-FA
- JEITA, JEDEC : SC-63, TO-252
- Minimum Packing Quantity : 700 pcs./reel

### Packing Type (TP-FA) : TL



### Electrical Connection



## 2SC4134

Continued from preceding page.

Parameter	Symbol	Conditions	Ratings	Unit
Collector Dissipation	PC		0.8	W
		T <sub>c</sub> =25°C	10	W
Junction Temperature	T <sub>j</sub>		150	°C
Storage Temperature	T <sub>stg</sub>		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

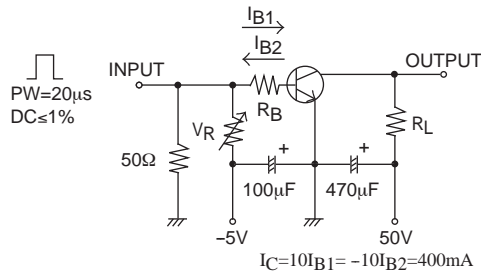
Electrical Characteristics at T<sub>a</sub>=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I <sub>CBO</sub>	V <sub>CB</sub> =100V, I <sub>E</sub> =0A			100	nA
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =4V, I <sub>C</sub> =0A			100	nA
DC Current Gain	h <sub>FE</sub>	V <sub>CE</sub> =5V, I <sub>C</sub> =100mA	100*		400*	
Gain-Bandwidth Product	f <sub>T</sub>	V <sub>CE</sub> =10V, I <sub>C</sub> =100mA		120		MHz
Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =10V, f=1MHz		8.5		pF
Collector-to-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =400mA, I <sub>B</sub> =40mA		0.1	0.4	V
Base-to-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =400mA, I <sub>B</sub> =40mA		0.85	1.2	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I <sub>C</sub> =10μA, I <sub>E</sub> =0A	120			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I <sub>C</sub> =1mA, R <sub>BE</sub> =∞	100			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I <sub>E</sub> =10μA, I <sub>C</sub> =0A	6			V
Turn-ON Time	t <sub>on</sub>	See specified Test Circuit.		80		ns
Storage Time	t <sub>stg</sub>			850		ns
Fall Time	t <sub>f</sub>			50		ns

\* : The 2SC4134 is classified by 100mA h<sub>FE</sub> as follows :

Rank	R	S	T
h <sub>FE</sub>	100 to 200	140 to 280	200 to 400

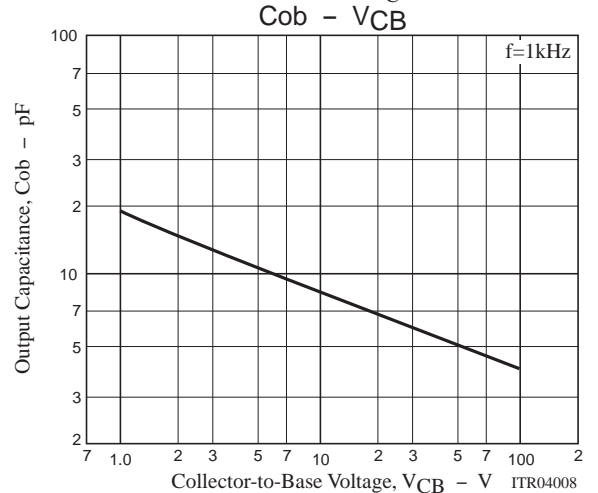
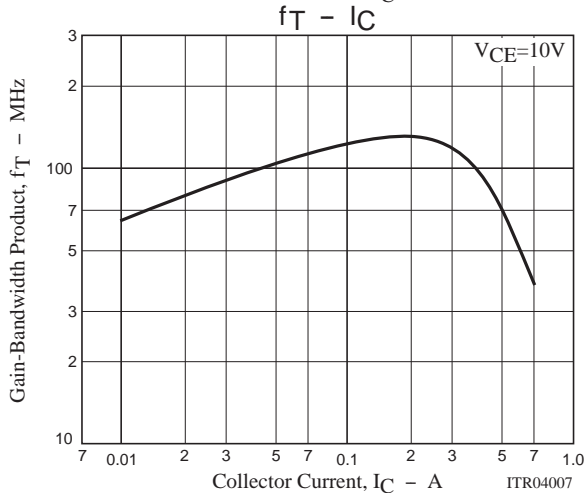
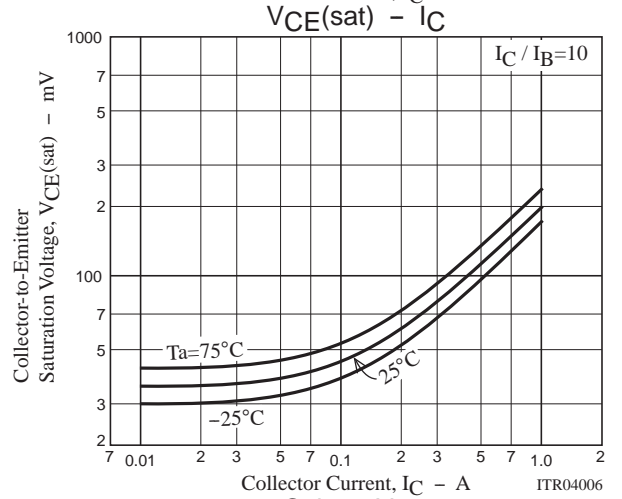
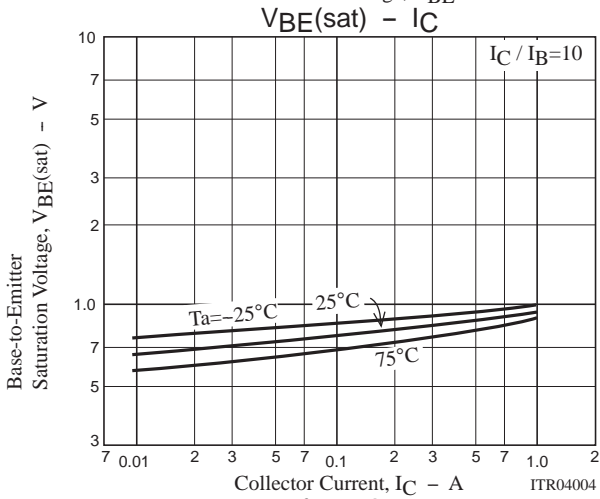
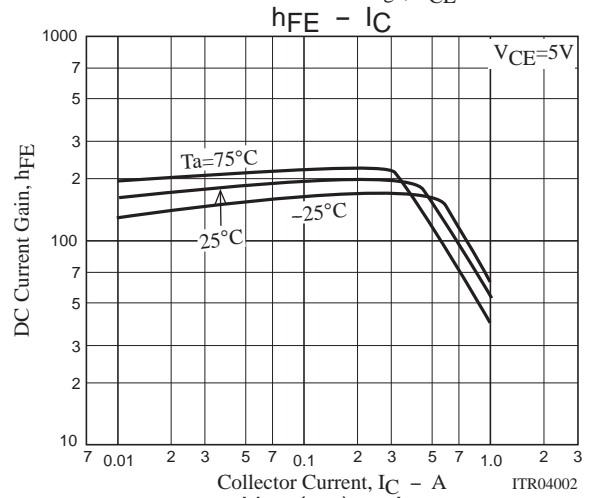
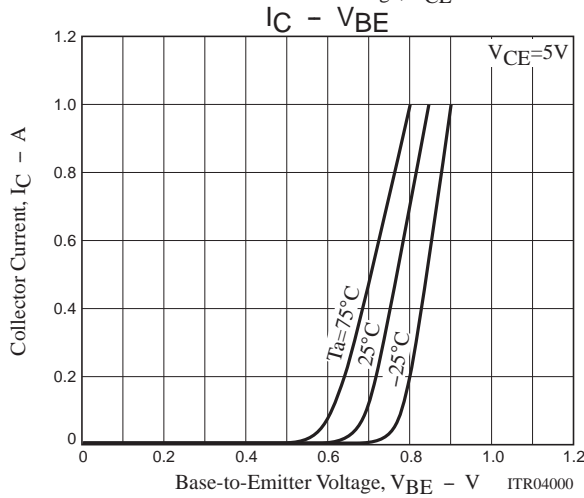
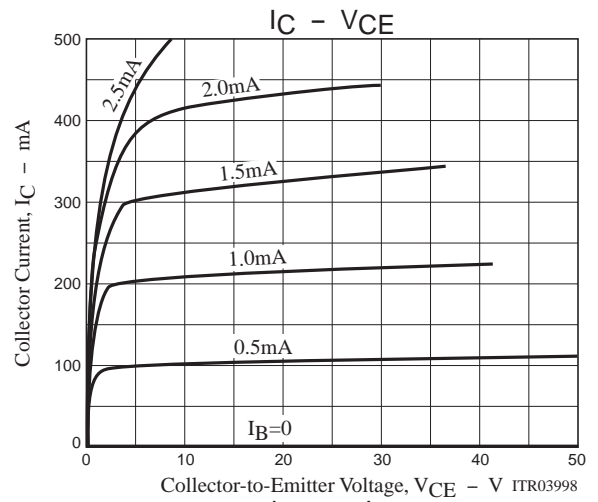
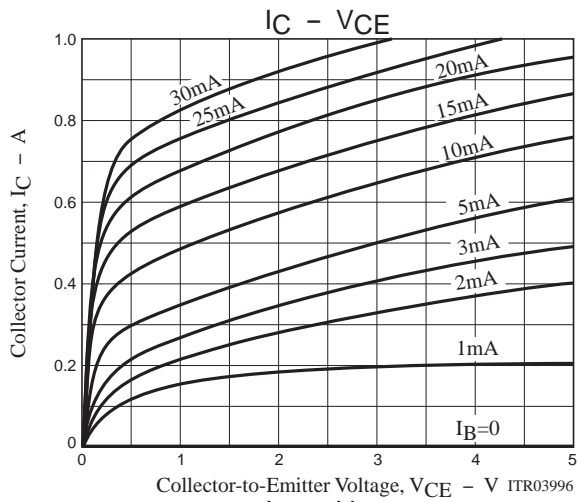
## Switching Time Test Circuit



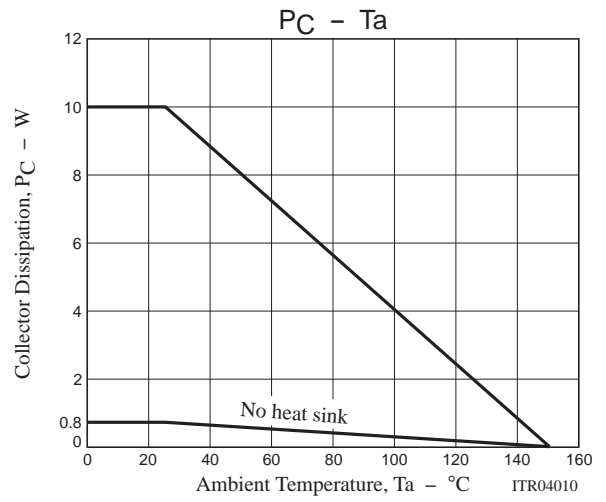
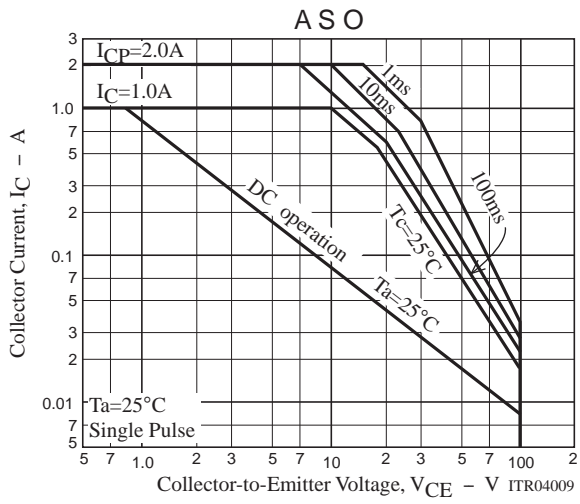
## Ordering Information

Device	Package	Shipping	memo
2SC4134S-E	TP	500pcs./bag	Pb Free
2SC4134T-E	TP	500pcs./bag	
2SC4134S-TL-E	TP-FA	700pcs./reel	
2SC4134T-TL-E	TP-FA	700pcs./reel	

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2SC4134



2SC4134

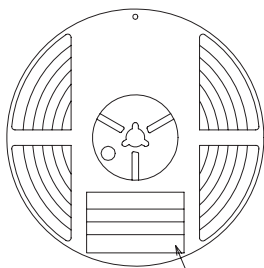
Taping Specification

2SC4134S-TL-E, 2SC4134T-TL-E

Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
TP-FA	TP	700	2,100	12,600	3 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

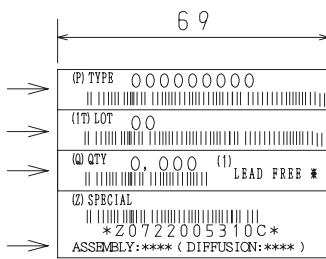
Packing method



Type No.  
LOT No.  
Quantity  
Origin

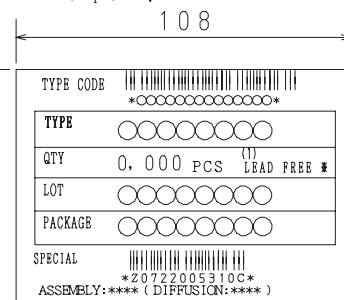
Reel label

Reel label, Inner box label (unit:mm)



Outer box label

It is a label at the time of factory shipments. The form of a label may change in physical distribution process.



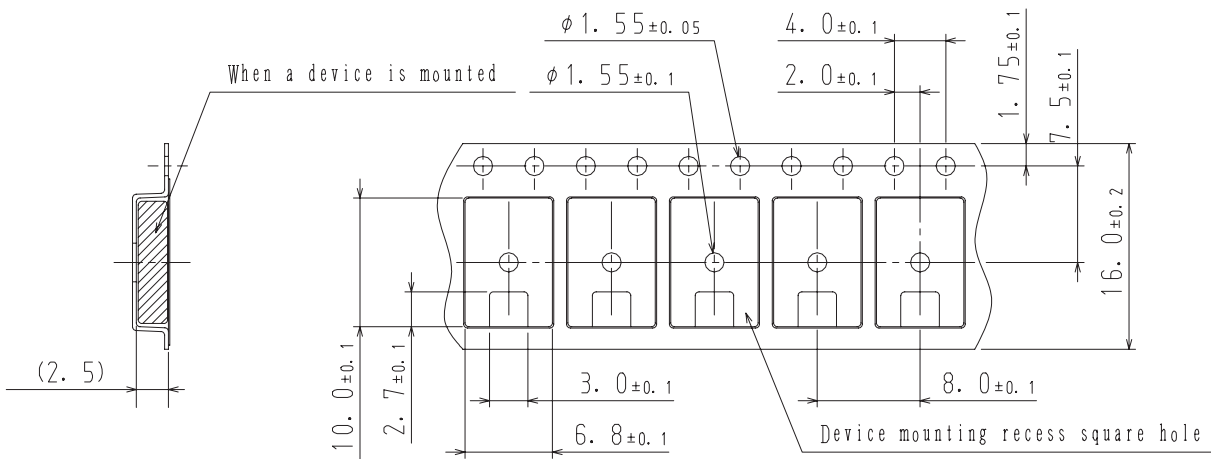
NOTE (1)

The LEAD FREE \* description shows that the surface treatment of the terminal is lead free.

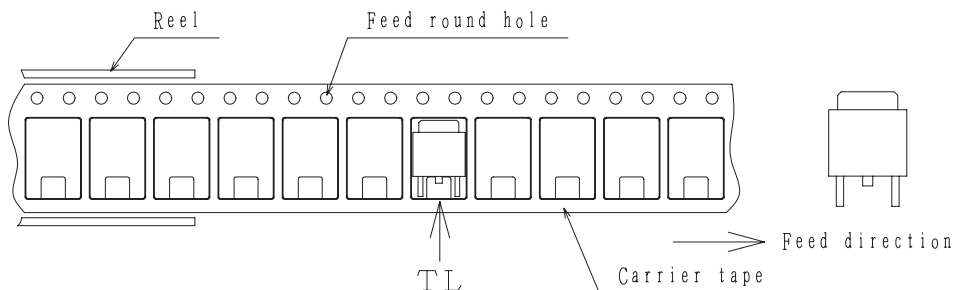
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

Taping configuration

1. Carrier tape size (unit:mm)



2. Device placement direction



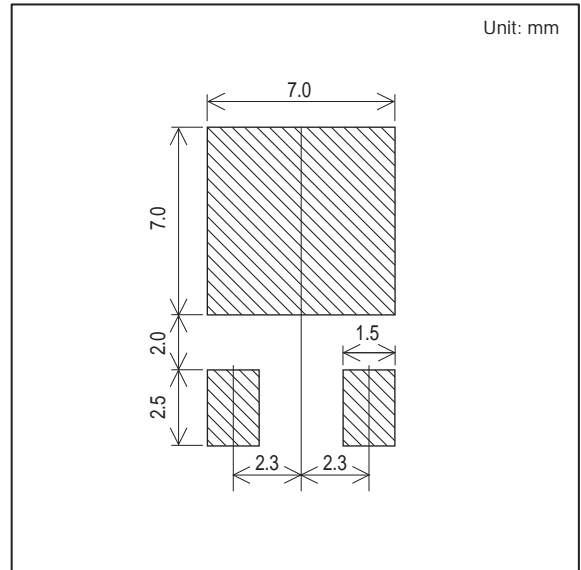
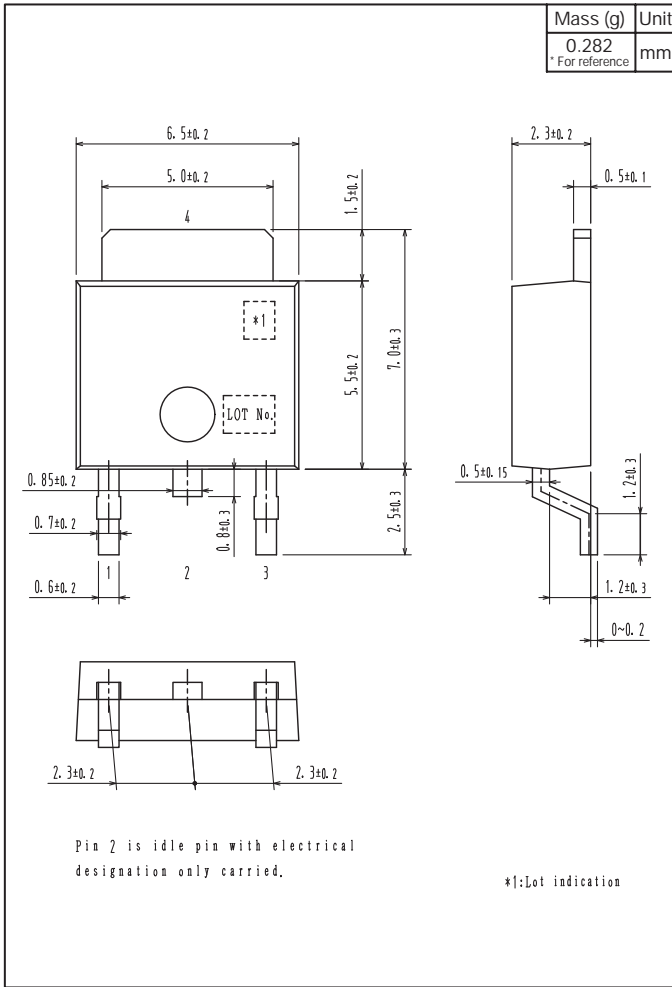
Those with one electrode terminal on the feed hole side.....TL

2SC4134

Outline Drawing

2SC4134S-TL-E, 2SC4134T-TL-E

Land Pattern Example





## 2SC4134

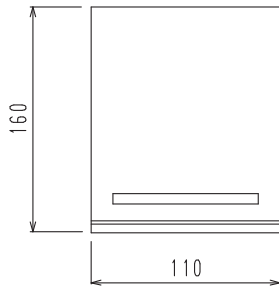
### Bag Packing Specification

2SC4134S-E, 2SC4134T-E

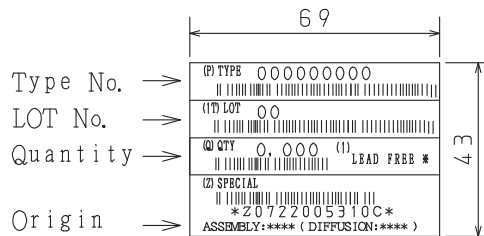
#### 1. Packing Format

Package Name	Maximum Number of devices contained (pcs)			
	Bag	Inner box	Outer box	
TP	500	B-1	A-1	A-2
		10,000	50,000	30,000
	Packing format (Dimensions:mm (external))			
		Inner box	Outer box	
		B-1	A-1	A-2
		445×225×55	470×250×300	470×250×190

#### 2. Bag dimensions (unit:mm)



#### 3. Bag label, Inner box label (unit:mm)



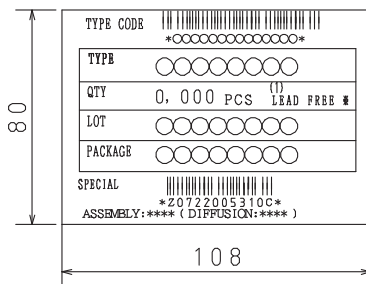
#### 4. Outer box label (unit:mm)

It is a label at the time of factory shipments.  
The form of a label may change in physical distribution process.

**NOTE (1)**

The LEAD FREE \* description shows that the surface treatment of the terminal is lead free.

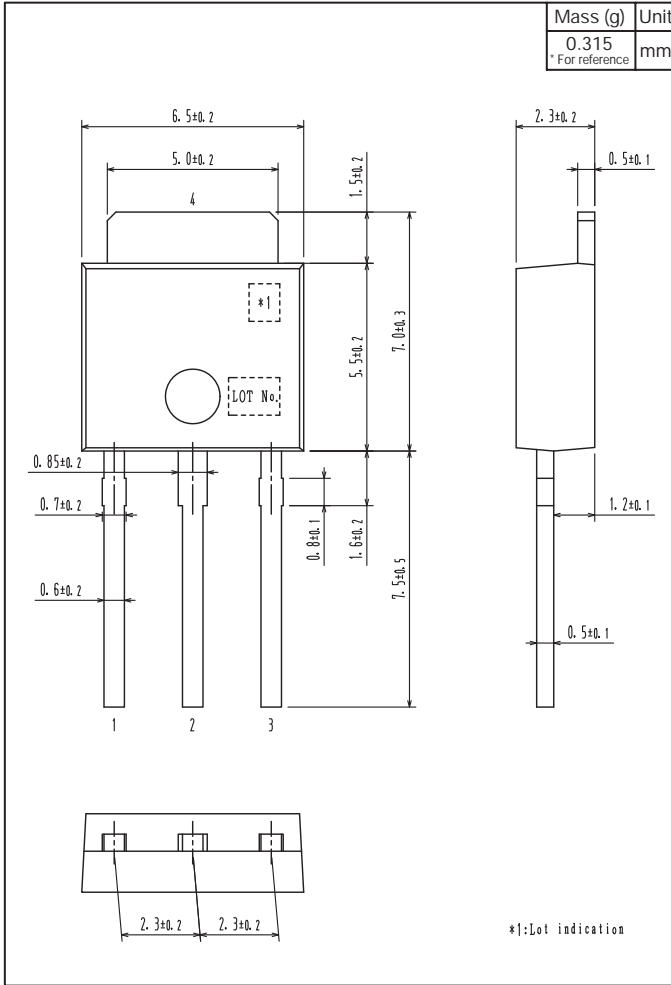
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3



## 2SC4134

### Outline Drawing

2SC4134S-E, 2SC4134T-E



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## 2SC4134

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